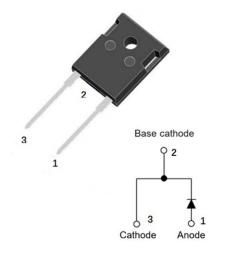
# YJD112020NYG4

# Silicon Carbide Schottky Diode

V <sub>RRM</sub>	1200V
I <sub>F (135°C)</sub>	27A
Q <sub>c</sub>	118nC



#### Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

#### **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

#### **Mechanical Data**

- Package: TO-247AC
- Terminals: Tin plated leads
- Polarity: As marked

#### ■Maximum Ratings (Tc=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D112020NYG4
Reverse voltage (Repetitive peak) @ T <sub>j</sub> =25°C	V <sub>RRM</sub>	V	1200
Reverse voltage (Surge peak) @ T <sub>j</sub> =25°C	V <sub>RSM</sub>	V	1200
Reverse voltage (DC) @ T <sub>j</sub> =25°C	V <sub>DC</sub>	V	1200
Continuous forward current @ $T_c=25^{\circ}C$			59
Continuous forward current @ T <sub>c</sub> =135°C	I <sub>F</sub>	А	27
Continuous forward current @ $T_c$ =151°C			20
Non-repetitive peak forward surge current @ T <sub>c</sub> =25°C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	160
Power Dissipation@ T <sub>c</sub> =25°C	Ρτοτ	W	230
Power Dissipation@ T <sub>c</sub> =110°C	F TOT		100
i²t Value@ T <sub>c</sub> =25°C ,tp=10ms	∫i²dt	A <sup>2</sup> S	128
Operating junction and Storage temperature range	$T_{j}$ , $T_{stg}$	°C	-55 to +175

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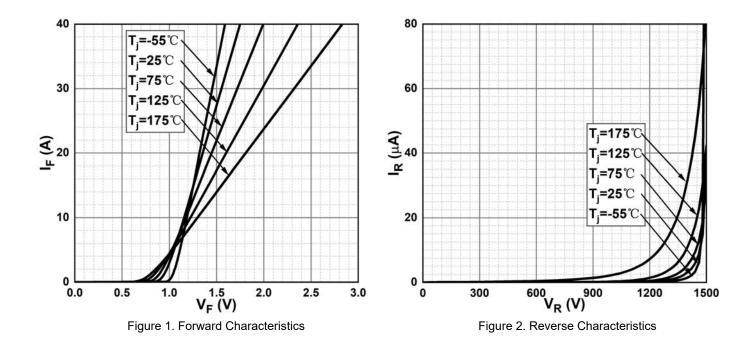
#### Electrical Characteristics

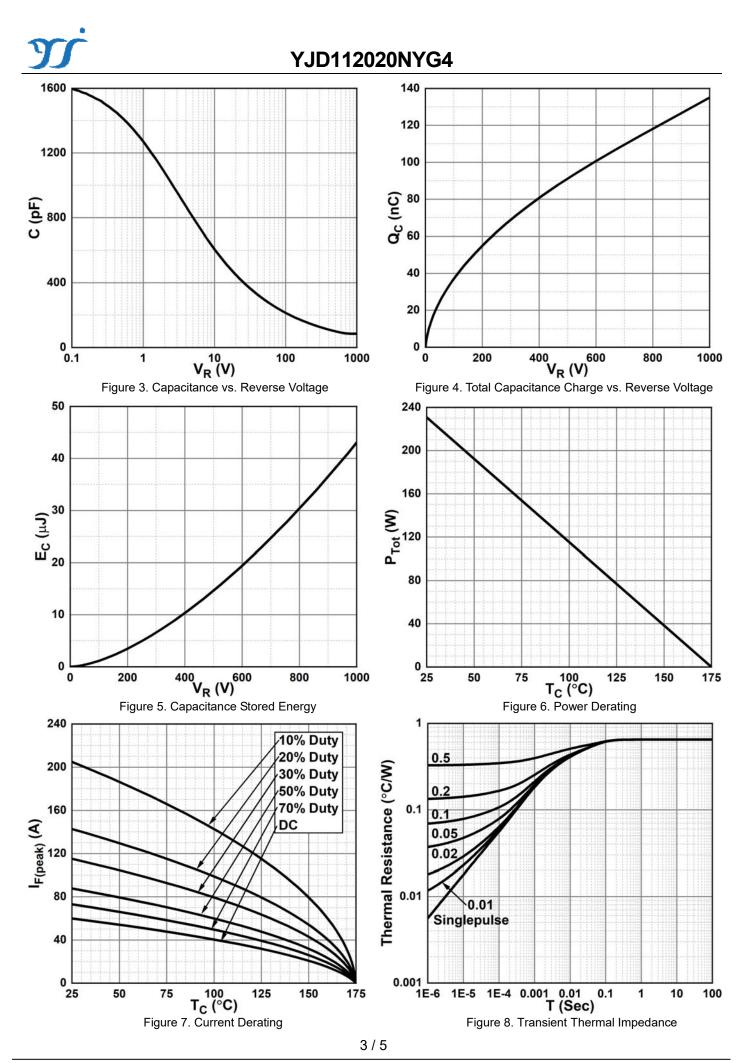
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drap		V	I <sub>F</sub> =20A, T <sub>j</sub> =25°C	1.36	1.60
Forward voltage drop	V <sub>F</sub>		I <sub>F</sub> =20A, T <sub>j</sub> =175°C	1.85	-
Reverse current	1	l <sub>R</sub> μA	V <sub>R</sub> =1200V, T <sub>j</sub> =25°C	0.5	25
Reverse current	I <sub>R</sub>		V <sub>R</sub> =1200V, T <sub>j</sub> =175°C	10	-
Total capacitive charge	Qc	nC	$V_R$ =800V, T <sub>j</sub> =25°C , $Q_C = \int_0^{VR} C(V) dV$	118	-
		pF	V <sub>R</sub> =0V, f=1MHZ	1626	-
Total capacitance	С		V <sub>R</sub> =400V, f=1MHZ	110	-
			V <sub>R</sub> =800V, f=1MHZ	85	-
Capacitance stored energy	Ec	μJ	V <sub>R</sub> =800V	30	-

## ■Thermal Characteristics (Ta=25 °C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C /W	0.65

### ■Typical Characteristics





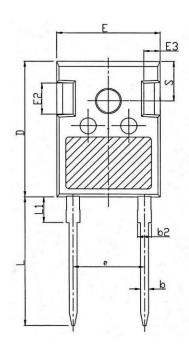
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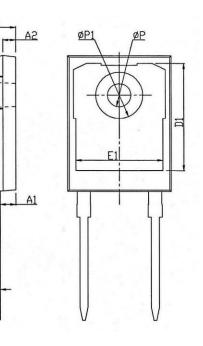


## Outline Dimensions

**TO-247AC** 

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TO-247AC				
Dim	Min	Max		
А	4.80	5.20		
A1	2.21	2.61		
A2	1.85	2.15		
b	1.11	1.36		
b2	1.91	2.21		
С	0.51	0.75		
D	20.70	21.30		
D1	16.25	16.85		
Е	15.50	16.10		
E1	13.00	13.60		
E2	4.80	5.20		
E3	2.30	2.70		
е	10.88BSC			
L	19.62	20.22		
L1	-	4.30		
ΦP	3.40	3.80		
ΦP1	-	7.30		
S	6.15BSC			

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